

# T0435N (U、Z、F)

## 主要参数 MAIN CHARACTERISTICS

$I_{T(RMS)}$	4A
$V_{DRM}$	800V
$I_{GT}$	35mA

### 用途

- 交流开关
- 相位控制

### APPLICATIONS

- AC switching
- Phase control

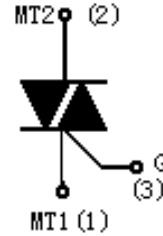
### 产品特性

- 玻璃钝化芯片，高可靠性和一致性
- 三象限可控硅，触发电流的一致性好
- 环保 RoHS 产品

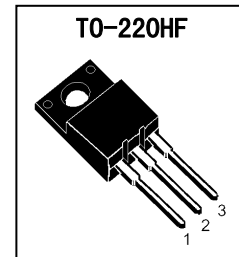
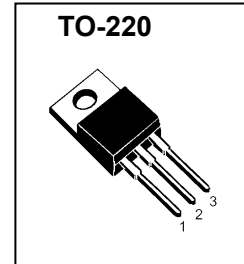
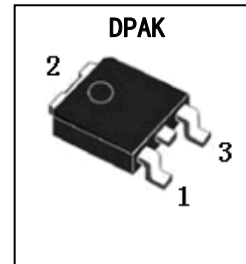
### FEATURES

- Glass-passivated mesa chip for reliability and uniform
- Uniform gate trigger currents in three quadrants
- RoHS products

## 封装 Package



序号 Pin	引线名称 Description
1	主电极 1 MT1
2	主电极 2 MT2
3	门极 G



## 订货信息 ORDER MESSAGES

订货型号 Order code	印记 Marking	封装 Package	包装 Packaging	器件重量 Device Weight
T0435NU-O-U-B-A	T0435NU	DPAK	编带 Tape	0.36g (typ)
T0435NZ-O-Z-N-B	T0435NZ	TO-220	条管 Tube	2.03g (typ)
T0435NF-O-HF-N-B	T0435NF	TO-220HF	条管 Tube	2.00g (typ)

## 概述 GENERAL DESCRIPTION

T0435N (U、Z、F) 是玻璃钝化芯片结构的三象限双向晶闸管，产品在第四象限不可触发，具有较高的使用可靠性。可适用于容易出现较高dV/dt或dI/dt的交流全波控制线路中，特别推荐应用与电感性负载控制（如电机控制线路）。器件封装形式有DPAK、TO-220、TO-220HF。

T0435N (U、Z、F) are Glass passivated three quadrant triacs, designed for high performance full-wave ac control applications where high static and dynamic dV/dt and high dI/dt can occur. They are specially recommended for use on inductive loads such as motor control circuits. Available packages are DPAK、TO-220、TO-220HF.

绝对最大额定值 ABSOLUTE RATINGS ( $T_C=25^\circ\text{C}$ )

项 目 Parameter	符 号 Symbol	试 验 条 件 Condition	数 值 Value	单 位 Unit
重复峰值断态电压 Repetitive peak off-state voltage	$V_{\text{DRM}}$		$\pm 800$	V
通态方均根电流 On-state RMS current	$I_{\text{T(RMS)}}$	full sine wave	4	A
非重复浪涌峰值通态电流 Non-repetitive surge peak on-state current	$I_{\text{TSM}}$	full sine wave, $t=20\text{ms}$	25	A
		full sine wave, $t=16.7\text{ms}$	27	A
	$I^2t$	$t=10\text{ms}$	3.1	$\text{A}^2\text{s}$
通态电流临界上升率 Repetitive rate of rise of on-state current after triggering	$di/dt$	$I_{\text{TM}}=6\text{A}$ , $I_{\text{G}}=0.2\text{A}$ , $di_{\text{G}}/dt=0.2\text{A}/\mu\text{s}$	100	$\text{A}/\mu\text{s}$
峰值门极电流 Peak gate current	$I_{\text{GM}}$		2	A
峰值门极电压 Peak gate voltage	$V_{\text{GM}}$		5	V
峰值门极功率 Peak gate power	$P_{\text{GM}}$		5	W
平均门极功率 Average gate power	$P_{\text{G(AV)}}$	over any 20ms period	0.5	W
存储温度 Storage temperature	$T_{\text{stg}}$		-40~150	$^\circ\text{C}$
操作结温 Operation junction temperature	$T_{\text{VJ}}$		125	$^\circ\text{C}$



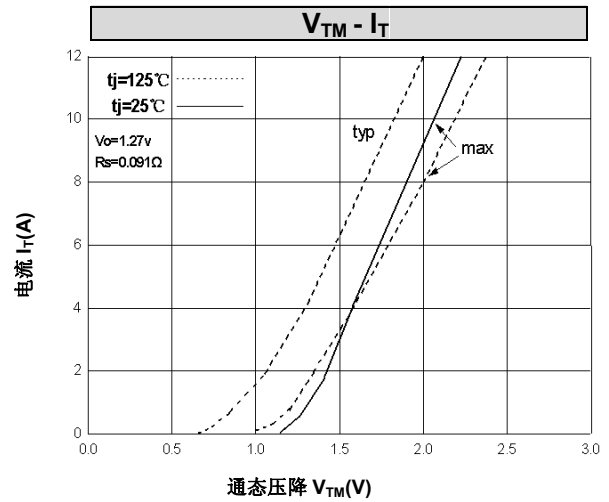
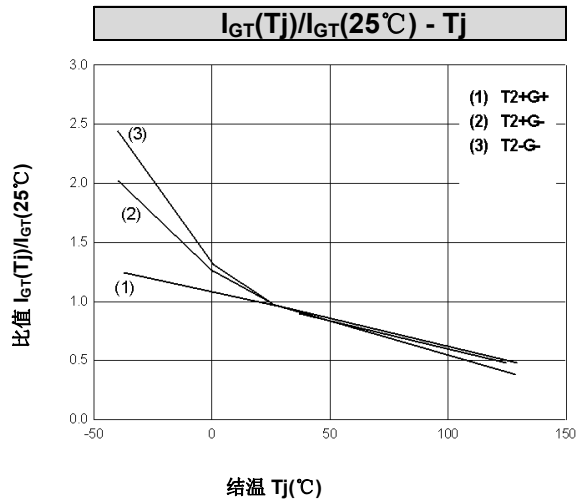
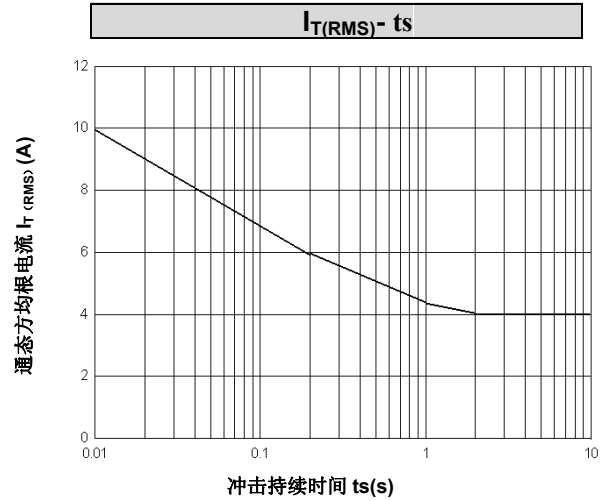
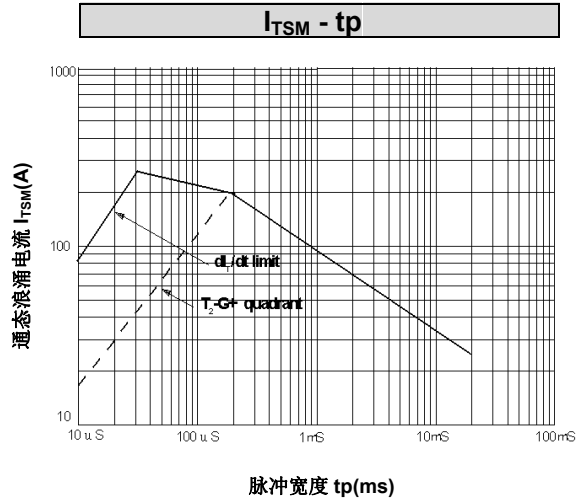
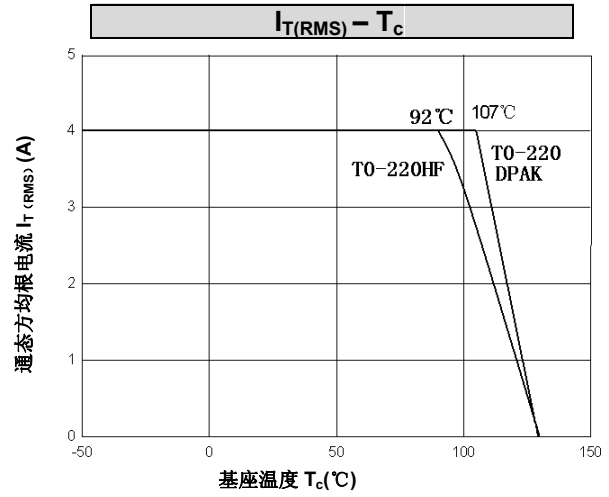
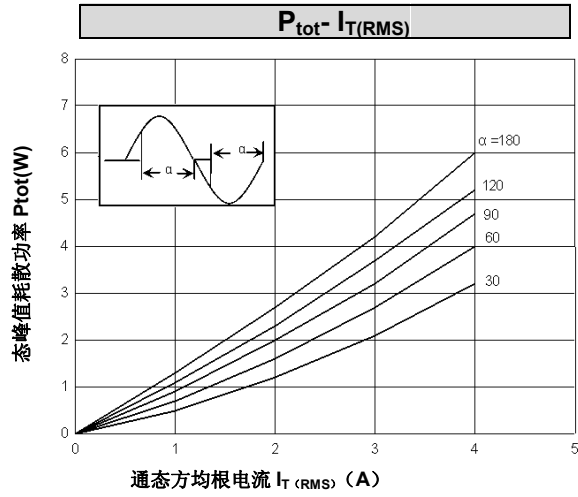
电特性 ELECTRICAL CHARACTERISTIC (T<sub>c</sub>=25°C)

项 目 Parameter	符 号 Symbol	测 试 条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit	
峰值重复断态电流 Peak Repetitive Blocking Current	I <sub>DRM</sub>	V <sub>DM</sub> =800V, T <sub>j</sub> =125°C, gate open	-	-	0.5	mA	
峰值通态电压 Peak on-state voltage	V <sub>TM</sub>	I <sub>TM</sub> =5A	-	1.4	1.7	V	
门极触发电流 Gate trigger current	I <sub>GT</sub>	V <sub>DM</sub> =12V, R <sub>L</sub> =100Ω	MT1(-),MT2(+),G(+)	2	-	35	mA
			MT1(-),MT2(+),G(-)	2	-	35	mA
			MT1(+),MT2(-),G(-)	2	-	35	mA
门极触发电压 Gate trigger voltage	V <sub>GT</sub>	V <sub>DM</sub> =12V, R <sub>L</sub> =100Ω	MT1(-),MT2(+),G(+)	-	0.7	1.5	V
			MT1(-),MT2(+),G(-)	-	0.7	1.5	V
			MT1(+),MT2(-),G(-)	-	0.7	1.5	V
维持电流 Holding current	I <sub>H</sub>	V <sub>DM</sub> =12V, I <sub>GT</sub> =0.1A	-	-	30	mA	
擎住电流 Latching current	I <sub>L</sub>	V <sub>DM</sub> =12V, I <sub>GT</sub> =0.1A	MT1(-),MT2(+),G(+)	-	-	30	mA
			MT1(-),MT2(+),G(-)	-	-	45	mA
			MT1(+),MT2(-),G(-)	-	-	30	mA
断态临界电压上升率 Rise of off- state voltage	dV/dt	V <sub>DM</sub> =67% V <sub>DRM(MAX)</sub> , T <sub>j</sub> =125°C, gate open	1000	-	-	V/μs	
门极开通时间 Gate controlled turn-on time	tgt	I <sub>TM</sub> =6A, V <sub>DM</sub> =V <sub>DRM(MAX)</sub> , I <sub>G</sub> =0.1A, dI <sub>G</sub> /dt=5A/μs	-	2	-	Ms	

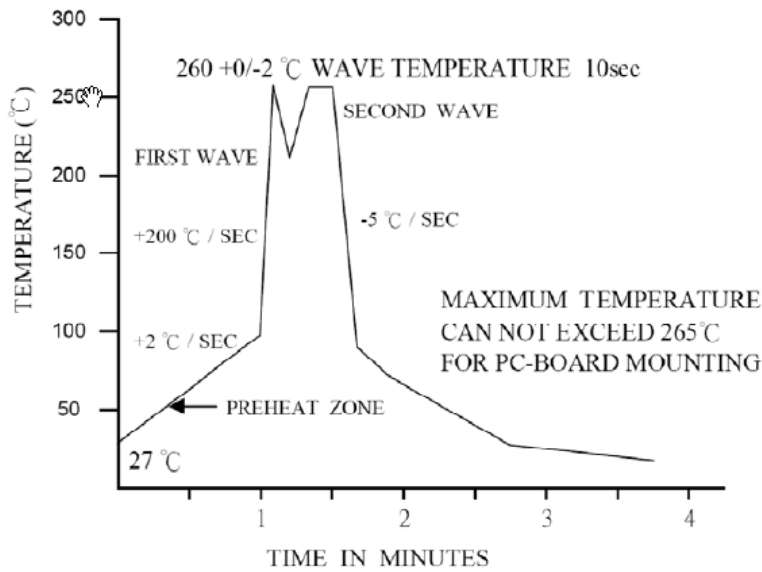
热特性 THERMAL CHARACTERISTIC

项 目 Parameter	符 号 Symbol	条 件 Condition	最小 Min	典型 Typ	最大 Max	单位 Unit
结到管壳的热阻 Thermal resistance junction to case	R <sub>th(j-c)</sub>	full cycle(DPAK、TO-220)			3.0	°C/W
结到管壳的热阻 Thermal resistance junction to case	R <sub>th(j-c)</sub>	full cycle(TO-220HF)			5.5	°C/W

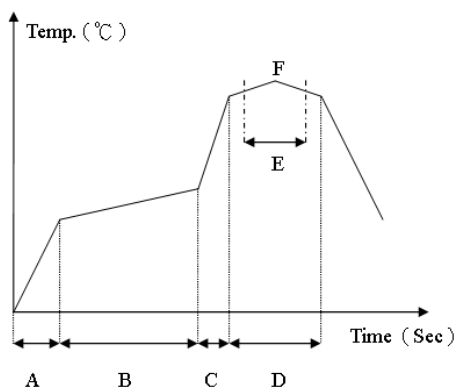
特征曲线 ELECTRICAL CHARACTERISTICS (curves)



回流焊（或波峰焊）曲线 REFLOW & WAVE SOLDER THERMAL PROFILE



Reflow Heat-resisting Temperature Condition



Profile Condition		Unit
A	Ramp Up	1~3 °C/Sec
B	Heat Time	60~180 Sec
	Heat Temp.	150~200 °C
C	Ramp Up	1~3 °C/Sec
D	Temp. Over 217°C	60~150 Sec
E	Temp. Over 245°C	20~40 Sec
F	Peak Temperature	260 °C
	Peak Hold Time	10 Sec
No of Time		2 Times

**Dip Soldering**

Flow soldering with bath. Flow soldering condition : 265 +5/-5°C 10 ± 0.5 Sec.

Times: 3 times

**Hand Soldering**

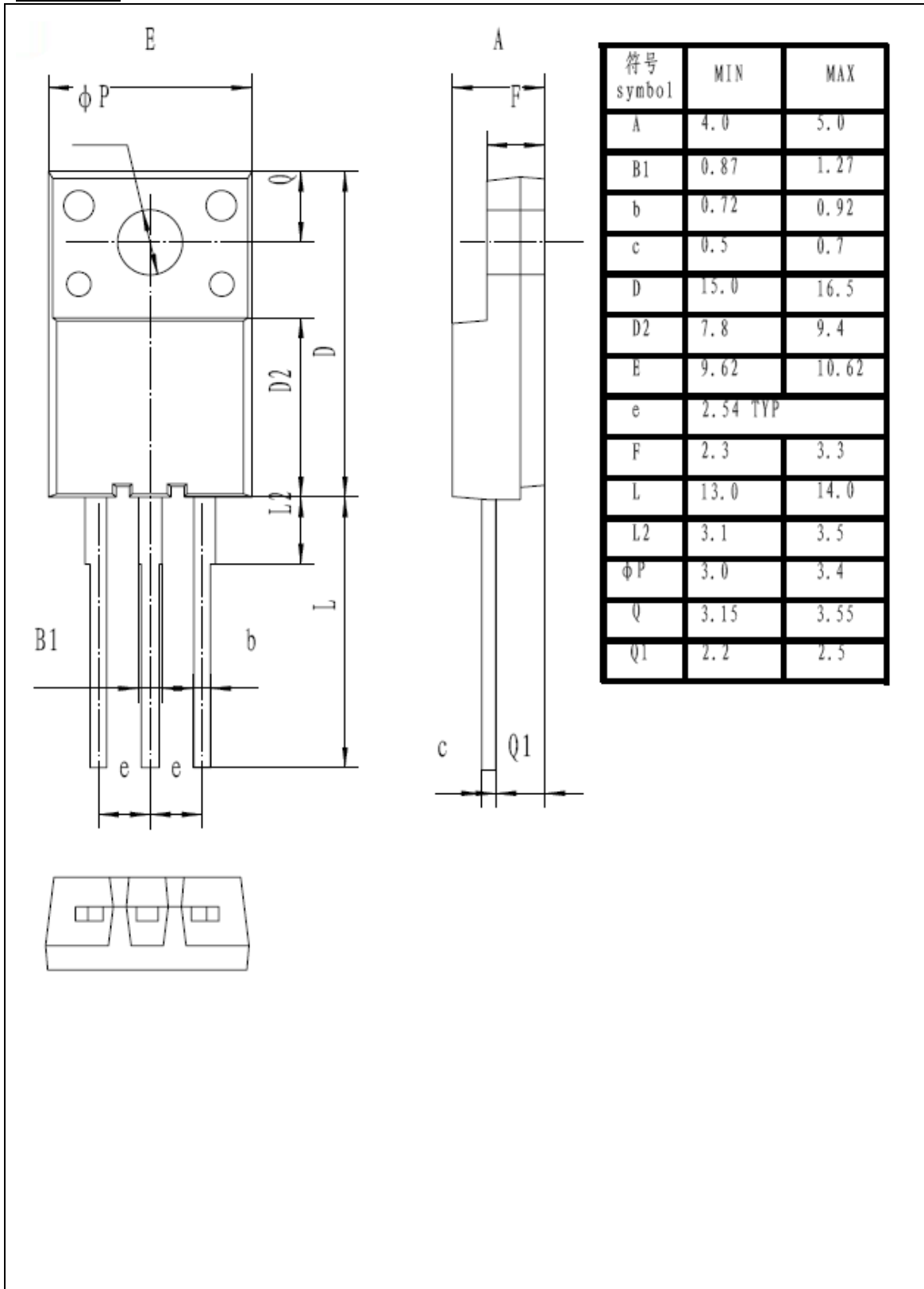
With soldering iron: 380°C 3 ± 0.5 Sec

Times: 2 times

外形尺寸 PACKAGE MECHANICAL DATA

TO-220HF

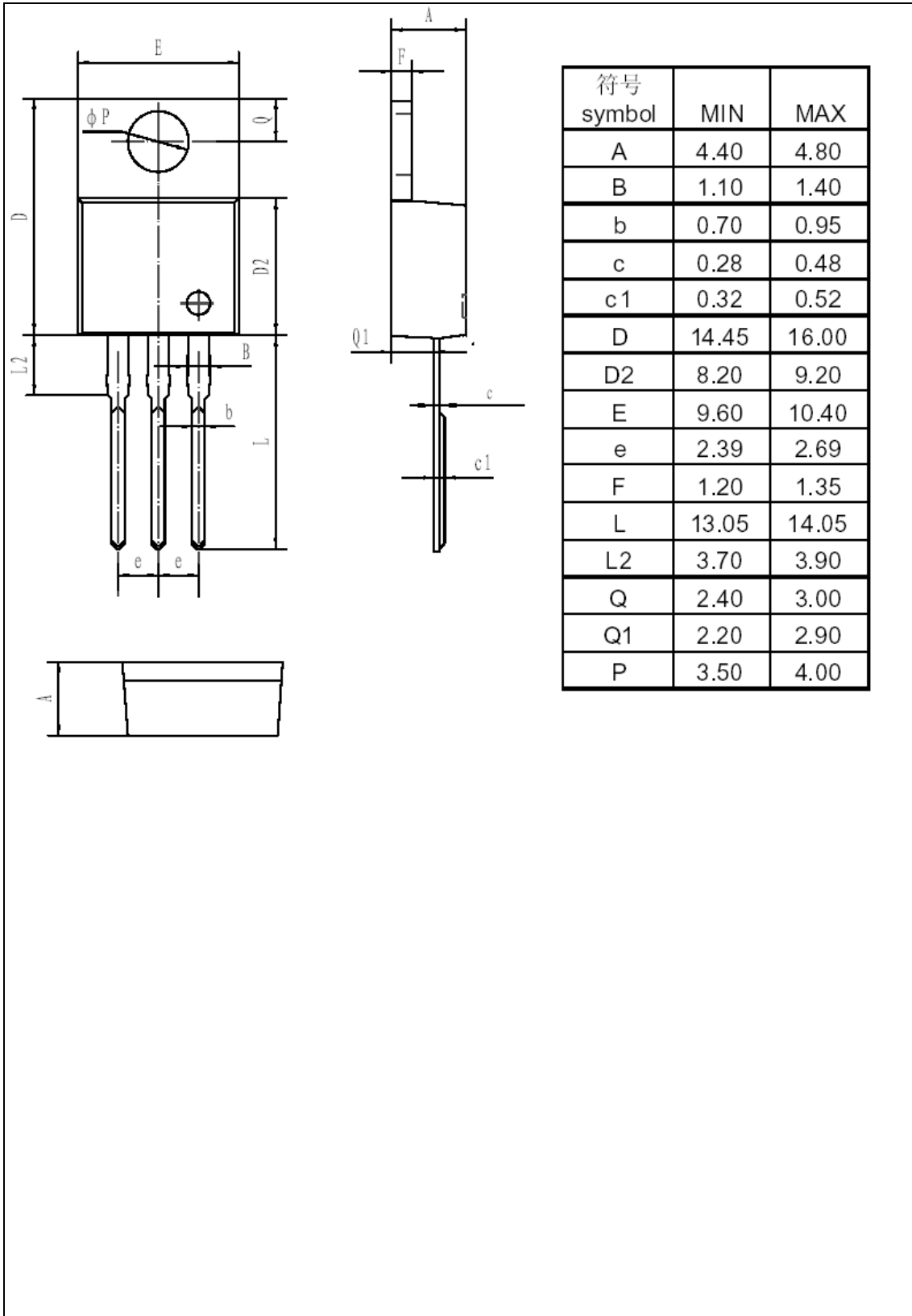
单位 Unit : mm



外形尺寸 PACKAGE MECHANICAL DATA

TO-220

单位 Unit : mm



外形尺寸 PACKAGE MECHANICAL DATA

**DPAK**

单位 Unit : mm

